LOW NOISE INFRARED DIODE LASER AT 905nm

RN-III-905/1~400mW

产品描述

It features ultra compact design, long lifetime, cost-effectiveness and easy

operation. They are used in measurement, communication, spectrum analysis, etc.

产品参数

RN-III-905/1~400mW	
Central wavelength (nm)	905±10
Operating mode	CW
Output power (mW)	>1, 100, 200,, 400
Power stability (rms, over 4 hours)	<1%, <2%, <3% (<0.5%, optional)
Transverse mode	Near TEM ₀₀
Noise of amplitude(rms,20Hz~20MHz)	<1%
Dimensions of beam at the aperture (mm)	~3.5
Beam divergence, full angle (mrad)	<1.0
Warm-up time (minutes)	<5
Beam height from base plate (mm)	24. 8
Operating temperature (° $\mathbb C$)	10~35
Power supply 85-264VAC	PSU-III-LED/ PSU-III-FDA (Frequency for 1Hz-30kHz)
100-240VAC	PSU-A-D (Frequency for 30kHz -100kHz)
TTL / Analog modulation	TTL or Analog with 1Hz-1kHz 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz optional
Expected lifetime (hours)	10000
Warranty	1 year



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